

BUL743

High voltage fast-switching NPN power transistor

Features

- Low spread of dynamic parameters
- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Electronic ballast for fluorescent lighting up to 256 W (8 x 32 W)
- Switch mode power supplies

Description

The device is manufactured using the diffused collector in planar technology adopting new and enhanced high voltage structure. It has an intrinsic ruggedness which enables the transistor to withstand an high collector current level during breakdown condition, without using the transil protection usually necessary in typical converters for lamp ballast.

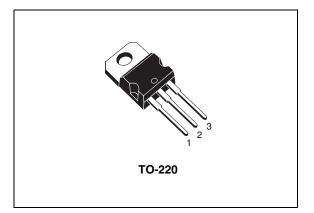


Figure 1. Internal schematic diagram

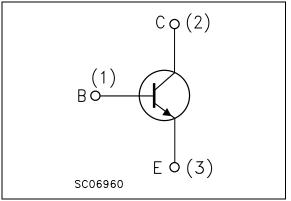


Table 1.	Device summary
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Order code	Marking	Package	Packaging
BUL743	BUL743	TO-220	Tube

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Doc ID 15263 Rev 3

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1 Electrical ratings

Table 2.	Absolute	maximum	ratings
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Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage ($V_{BE} = 0$)	1200	V
V _{CEO}	Collector-emitter voltage ($I_B = 0$)	500	V
V _{EBO}	Emitter-base voltage ($I_C = 0$, $I_B = 6$ A, $t_p < 10$ ms)	V _{(BR)EBO}	V
Ι _C	Collector current	12	А
I _{CM}	Collector peak current (t _P < 5 ms)	24	А
Ι _Β	Base current	6	А
I _{BM}	Base peak current (t _P < 5 ms)	12	А
P _{tot}	Total dissipation at $T_c = 25 \ ^{\circ}C$	100	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction - case	1.25	°C/W
R _{thj-amb}	Thermal resistance junction - ambient	62.5	°C/W



2 Electrical characteristics

(T_{case} = 25 °C unless otherwise specified)

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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 1200 V		0.2	10	μA
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CE} = 500 V		10	250	μA
V _{(BR)EBO}	Emitter base breakdown voltage (I _C = 0)	I _E = 1 mA	15	19	24	v
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage $(I_B = 0)$	I _C = 50 mA	500			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{C} = 3 A$ $I_{B} = 0.6 A$ $I_{C} = 10 A$ $I_{B} = 2.5 A$		0.15 0.6	0.5 1.5	V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 10 A I _B = 2.5 A		1.1	1.5	v
h _{FE} ⁽¹⁾	DC current gain		35 24	55 34	80 45	
t _s t _f	Resistive load Storage time Fall time	$\begin{split} I_{C} &= 6 \text{ A} & V_{CC} &= 125 \text{ V} \\ I_{B(on)} &= -I_{B(off)} &= 1.2 \text{ A} \\ I_{p} &= 300 \mu \text{s} & V_{BE(off)} &= -5 \text{ V} \end{split}$		2.5 400	3.8 500	µs ns
E _{ar}	Repetitive avalanche energy	$\label{eq:L} \begin{array}{l} L=2 \text{ mH} & C=1.8 \text{ nF} \\ V_{\text{BE(off)}}=-5 \text{ V} \end{array}$	3			mJ

Table 4. Electrical characteristics

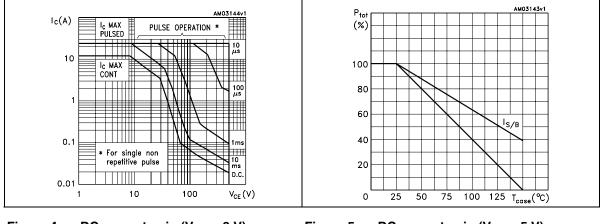
1. Pulsed duration = 300 μ s, duty cycle $\leq 1.5\%$



Electrical characteristics (curves) 2.1

Figure 2. Safe operating area

Figure 3. **Derating curve**





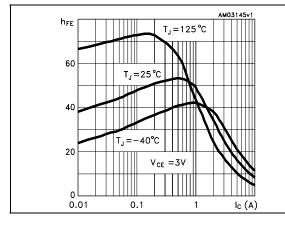


Figure 6. **Collector-emitter saturation** voltage



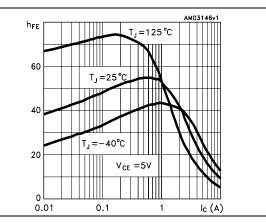
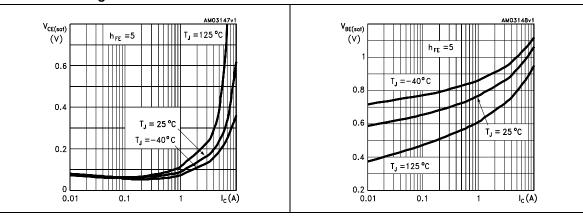


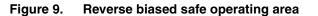
Figure 7. **Base-emitter saturation voltage**

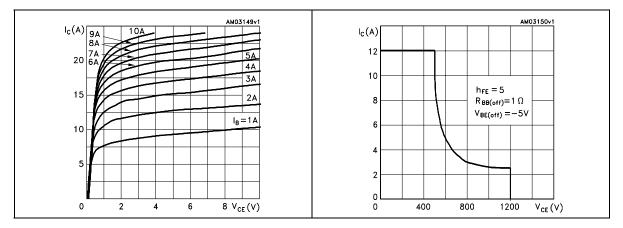


4/10

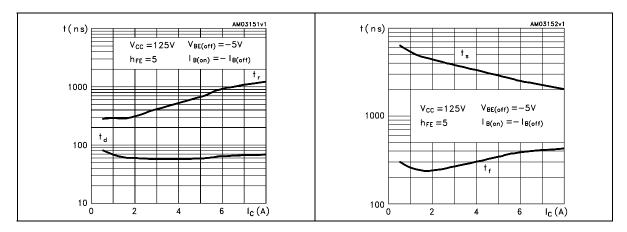
Doc ID 15263 Rev 3

Figure 8. Output characteristics









2.2 Test circuits

Figure 12. Energy rating test circuit

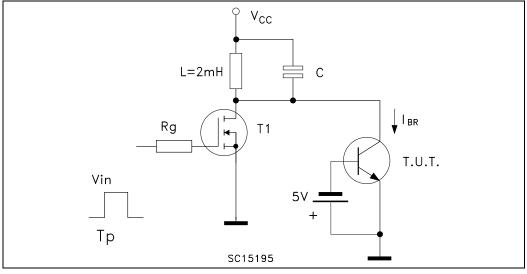
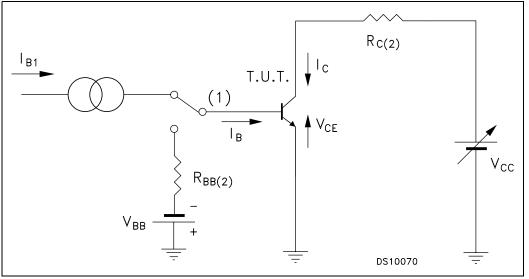


Figure 13. Resistive load switching test circuit



1. Fast electronic switch

2. Non-inductive resistor



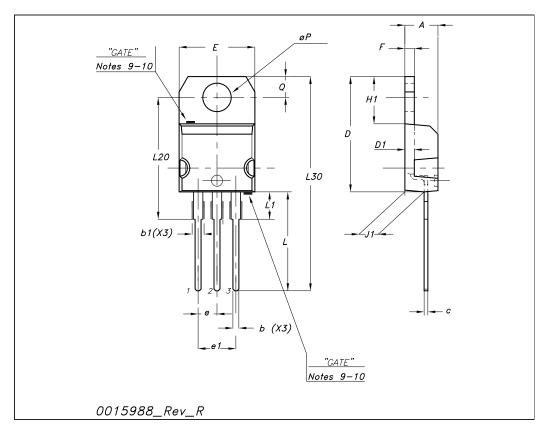
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.



57

Dim		mm			inch		
Dim	Min	Тур	Max	Min	Тур	Мах	
А	4.40		4.60	0.173		0.181	
b	0.61		0.88	0.024		0.034	
b1	1.14		1.70	0.044		0.066	
С	0.48		0.70	0.019		0.027	
D	15.25		15.75	0.6		0.62	
D1		1.27			0.050		
E	10		10.40	0.393		0.409	
е	2.40		2.70	0.094		0.106	
e1	4.95		5.15	0.194		0.202	
F	1.23		1.32	0.048		0.051	
H1	6.20		6.60	0.244		0.256	
J1	2.40		2.72	0.094		0.107	
L	13		14	0.511		0.551	
L1	3.50		3.93	0.137		0.154	
L20		16.40			0.645		
L30		28.90			1.137		
ØP	3.75		3.85	0.147		0.151	
Q	2.65		2.95	0.104		0.116	



Doc ID 15263 Rev 3

4 Revision history

Table 5.Document revision history

Date	Revision	Changes
09-Dec-2008	1	First release
20-Mar-2009	2	Added Section 2.1Section 2.1: Electrical characteristics (curves) on page 4
25-May-2009	3	Document status promoted from preliminary data to datasheet



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10/10

